



Optical modeling and simulation of thin-film Cu(In,Ga)Se_2 solar cells

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Outline

- Introduction
- Optical modeling of thin-film solar cells
- Optical simulator *SunShine*
- Results
 - Optical simulation of thin Cu(In,Ga)Se_2 solar cells
- Conclusions

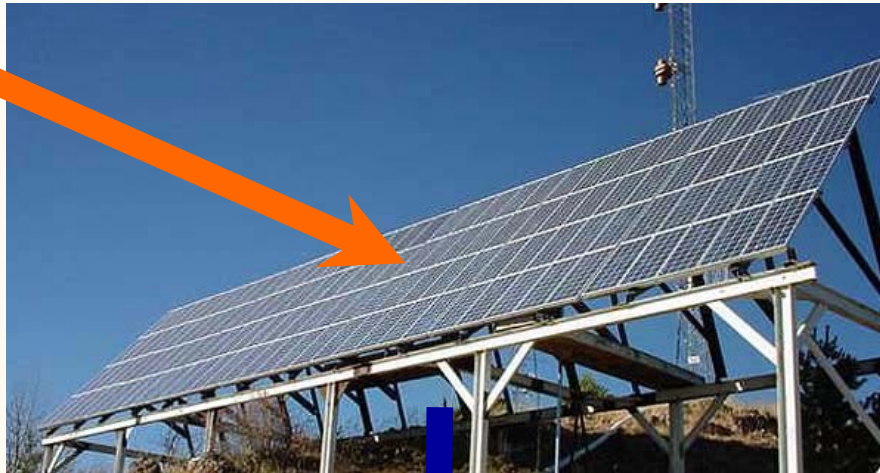


Introduction

Solar energy



Solar cell (PV modules)

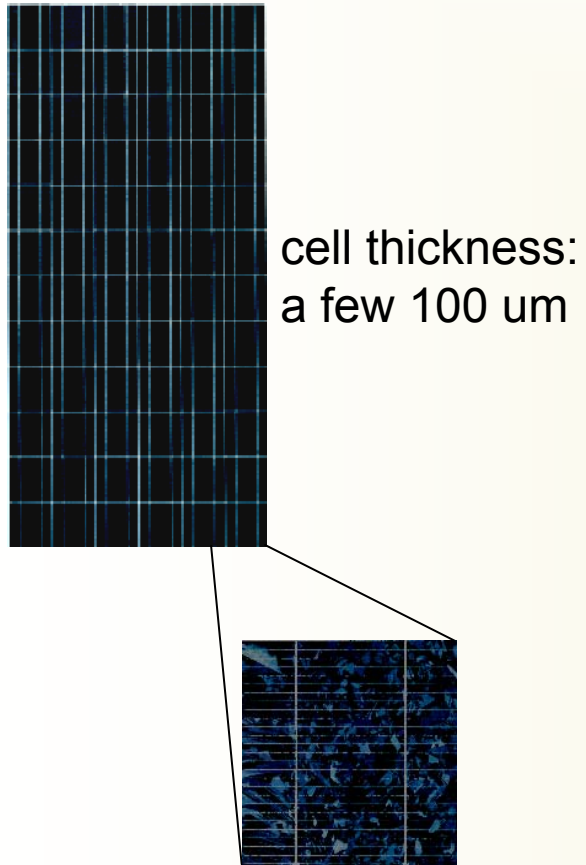


Electrical energy

> 30 % growth in module production per year

Introduction

conventional wafer-based solar cells



thin-film (TF) solar cells

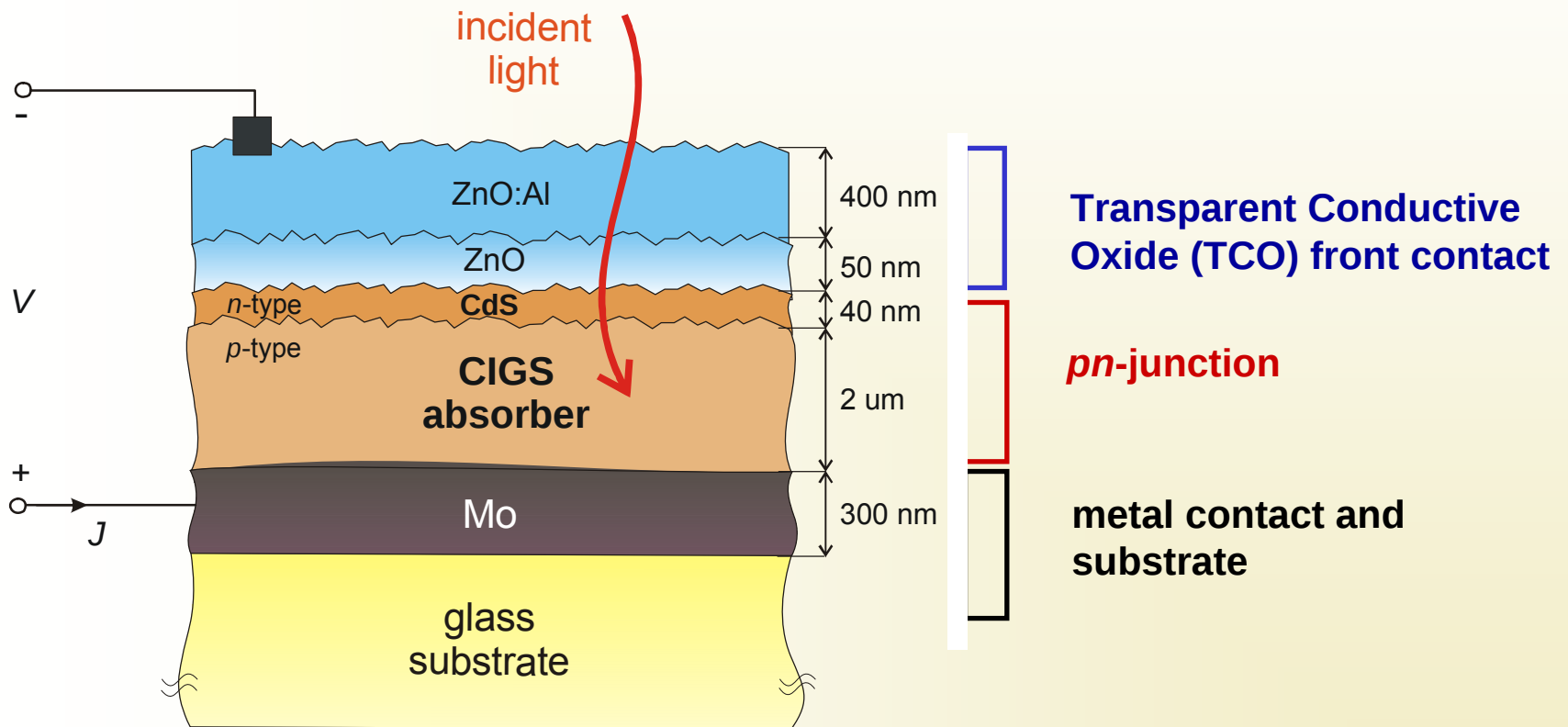


cell thickness:
a few μm or less

- lower material consumption
- low temperature processes
- possibility of being flexible

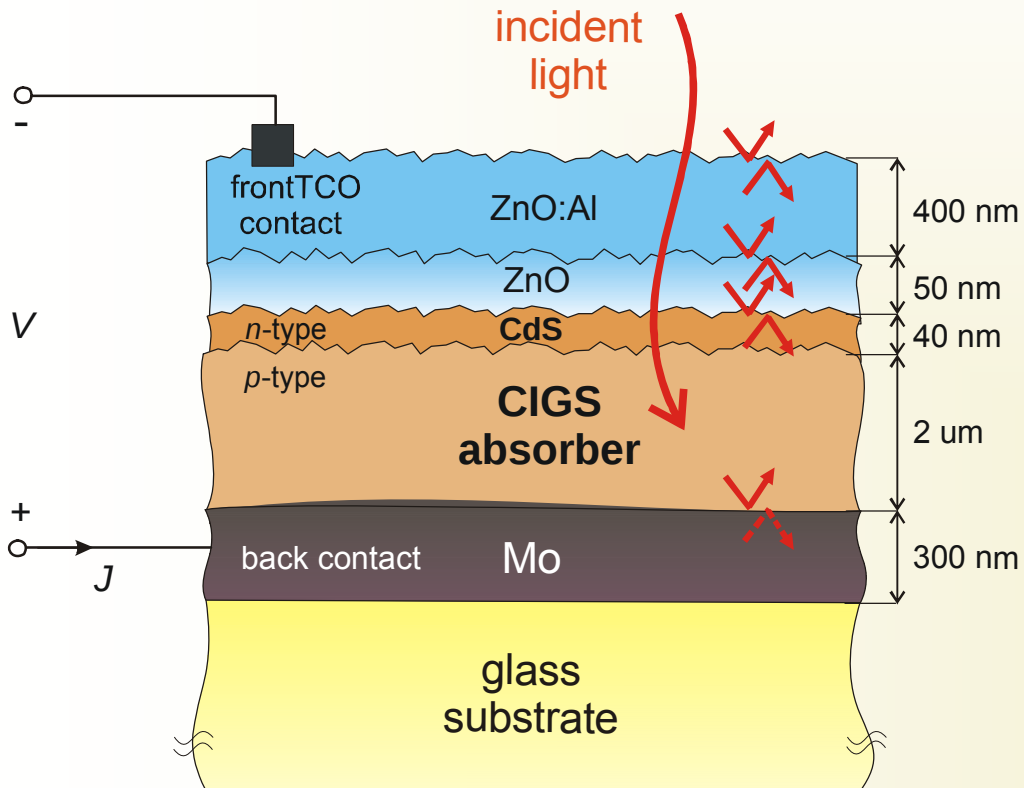
Introduction

$\text{Cu}(\text{In,Ga})\text{Se}_2$ (CIGS) thin-film solar cell:



Introduction

TF solar cell as an optical system:



Optical features:

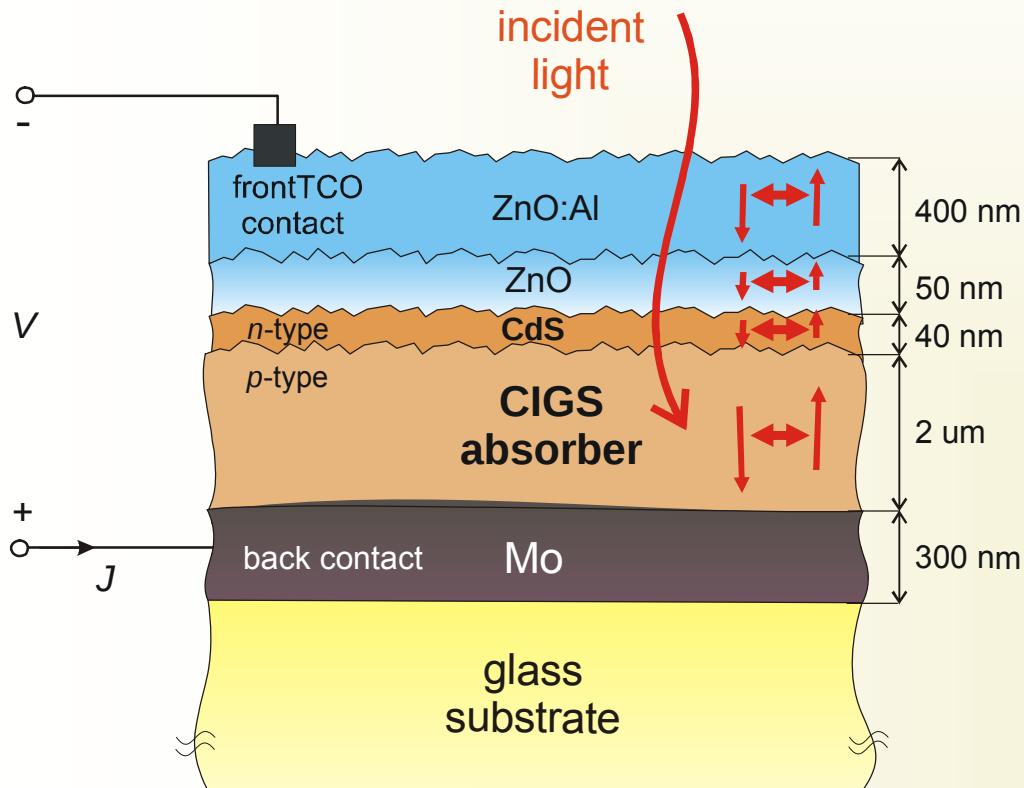
- multilayer structure



multiple R and T !

Introduction

TF solar cell as an optical system:



Optical features:

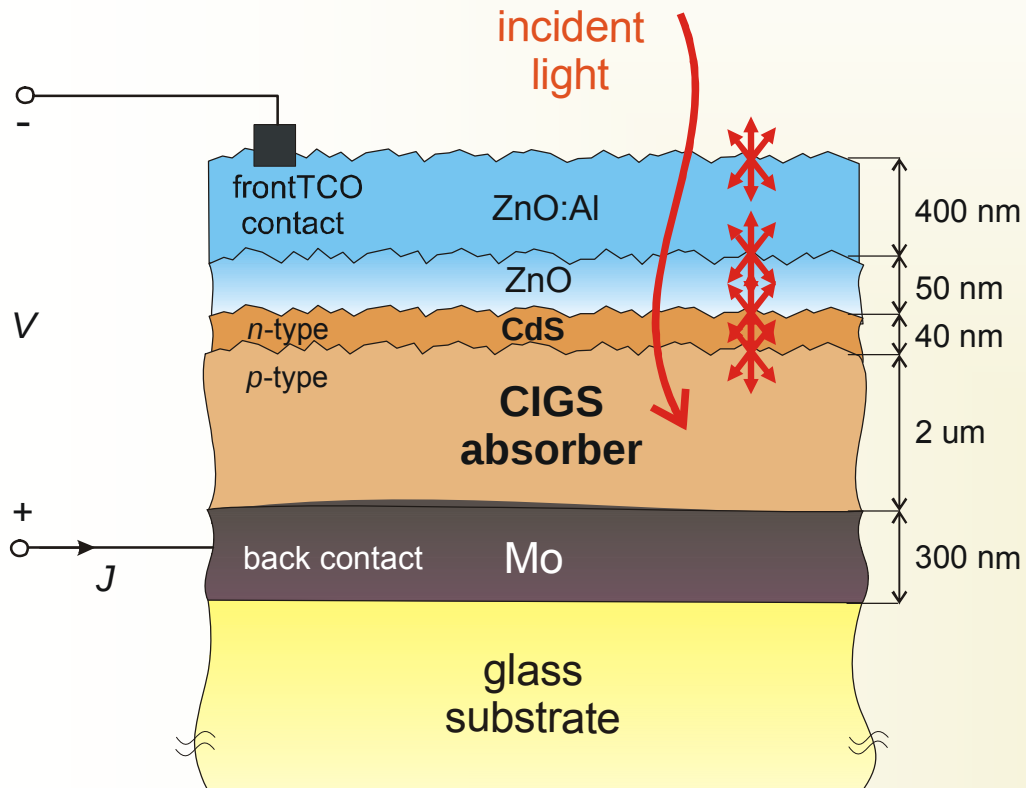
- multilayer structure
- layers in nm range



interferences!

Introduction

TF solar cell as an optical system:



Optical features:

- multilayer structure
- layers in nm range
- textured interfaces

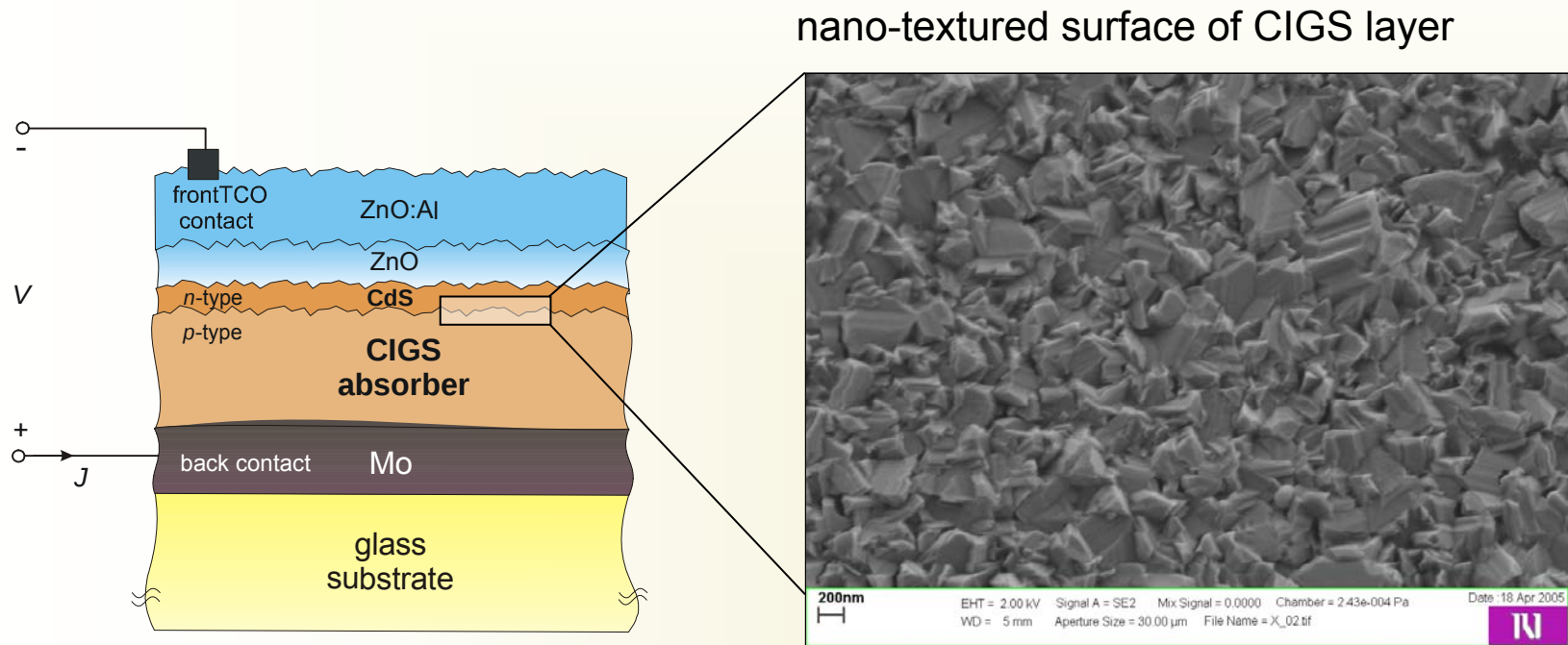


light scattering!



Optical modeling of TF solar cells

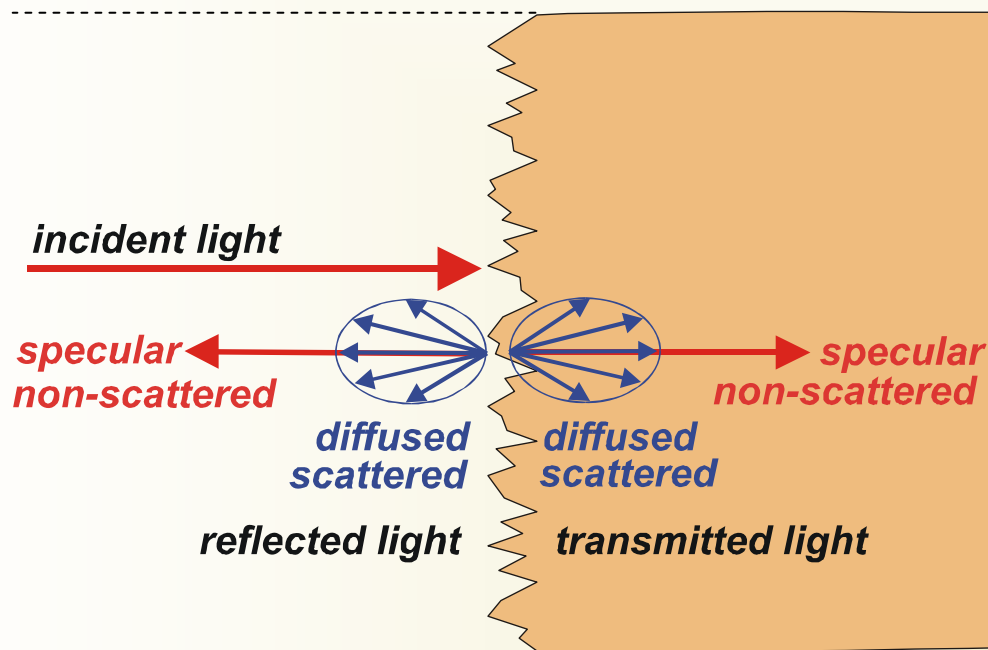
Optical modeling of light scattering



Optical modeling of light scattering

Light scattering at nano-textured interfaces:

- Specular (non-scattered) light
- Scattered (diffused) light



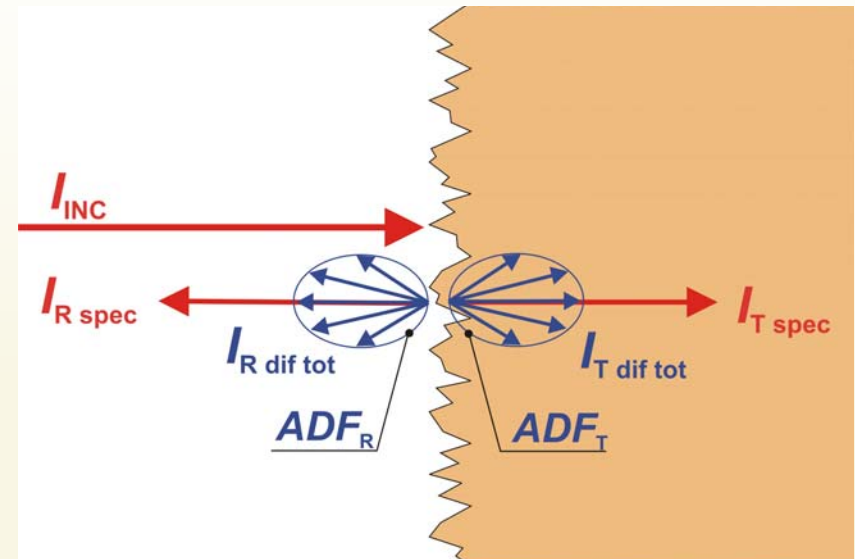
Optical modeling of light scattering

Descriptive scattering parameters:

1. Haze (scattering level)

$$H_R = \frac{I_{R \text{ dif tot}}}{I_{R \text{ dif tot}} + I_{R \text{ spec}}}$$

$$H_T = \frac{I_{T \text{ dif tot}}}{I_{T \text{ dif tot}} + I_{T \text{ spec}}}$$



2. Angular distribution functions (directions)

$$ADF_R(\varphi_{\text{scatt}})$$

$$ADF_T(\varphi_{\text{scatt}})$$

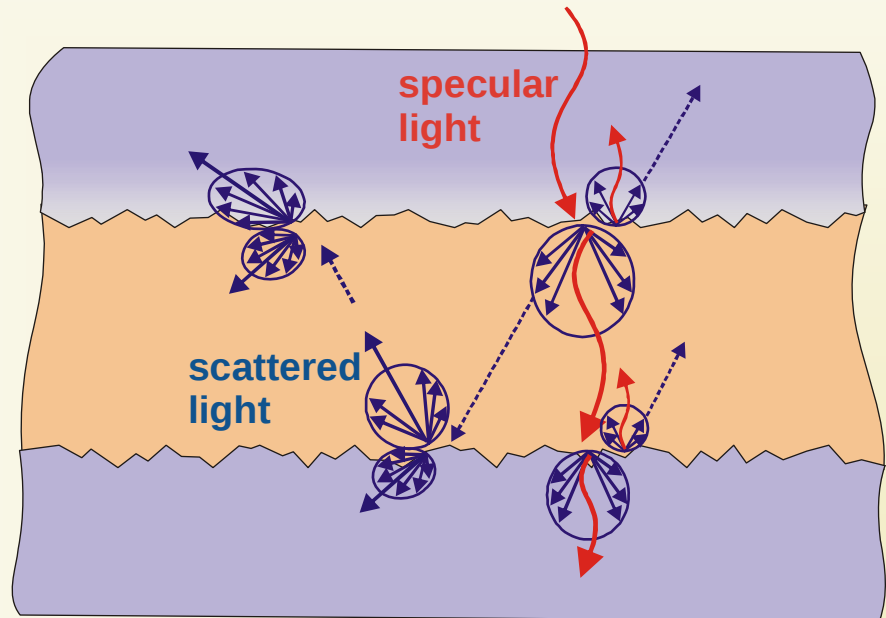
$$I_{T \text{ dif tot}} \begin{array}{c} \text{Diagram of a circle with arrows representing light distribution at an angle } \varphi \end{array} I_{T \text{ dif}}(\varphi) = ADF_T(\varphi) I_{T \text{ dif tot}}$$



Optical simulator SunShine

Optical simulator SunShine

- 1-D semi-coherent optical model [J. Krc et al., Progress in Photovoltaics 11 (2003) 15.]
- specular light -
electromagnetic waves (coherent)
- scattered light -
light rays (incoherent)



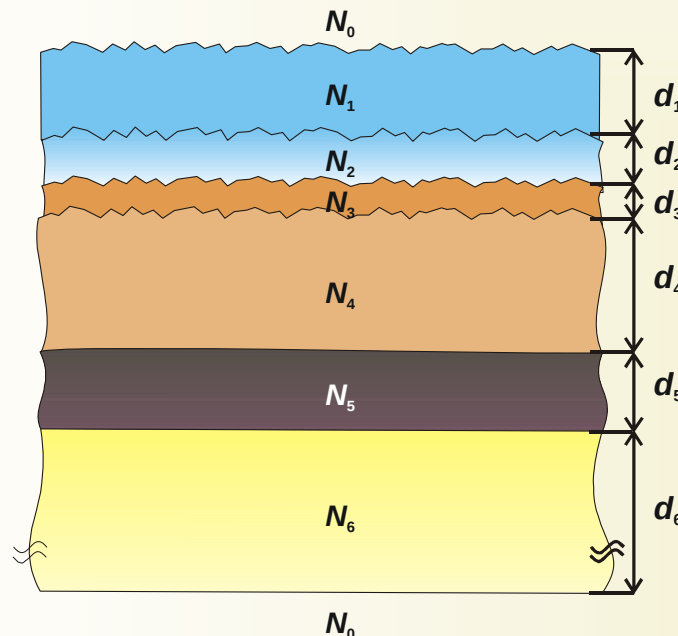
Optical simulator SunShine

- 1-D semi-coherent optical model [J. Krc et al., Progress in Photovoltaics 11 (2003) 15.]

Main input parameters (structure description):

- Complex refractive indexes and thicknesses of layers

$$N(\lambda) = n(\lambda) - jk(\lambda)$$



Optical simulator SunShine

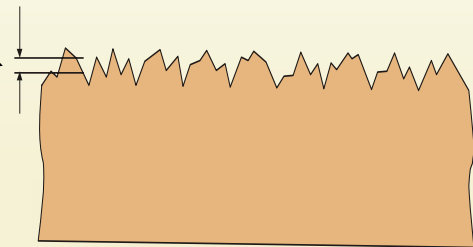
- 1-D semi-coherent optical model [J. Krc et al., Progress in Photovoltaics 11 (2003) 15.]

Main input parameters (structure description):

- Complex refractive indexes and thicknesses of layers
- *Haze* and *ADF* of textured interfaces and root-mean-square roughness, σ_{rms} , of interfaces

Calibrated equations of scalar scattering theory
(for details refer to our NUSOD paper)

$\sigma_{\text{rms}}, n, \lambda \rightarrow H_{\text{R}}, H_{\text{T}}$ for internal interfaces





Optical simulator *SunShine*

- 1-D semi-coherent optical model [J. Krc et al., Progress in Photovoltaics 11 (2003) 15.]

Main input parameters (structure description):

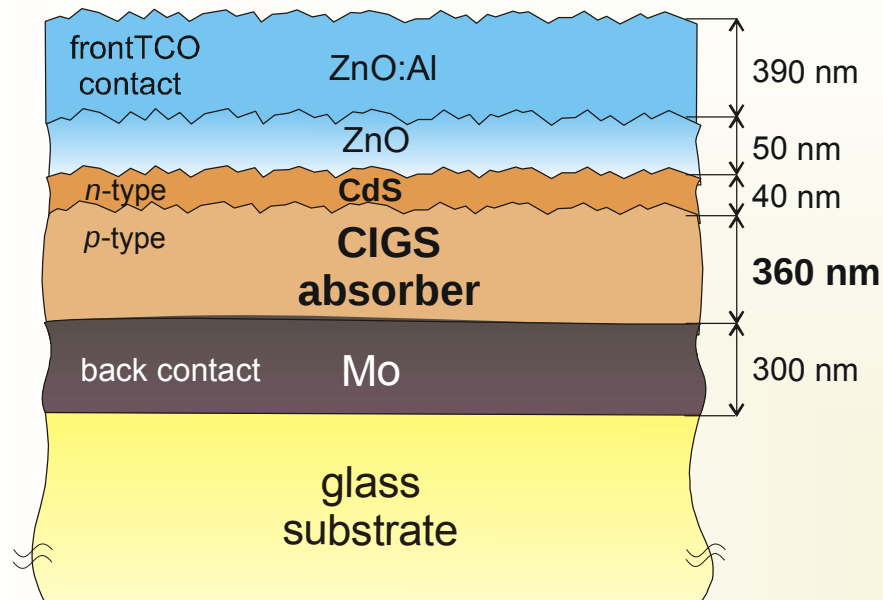
- Complex refractive indexes and thicknesses of layers
- H and ADF of textured substrates
and measured root-mean square roughness of interfaces

Main ourput results:

- Optical reflectance from the structure
- Absorptances in individual layers
- Charge-carrier generation-rate profile

Simulations

Simulated structure:



Extremely thin
CIGS absorber

- Thinning down CIGS absorber below 1 μm
(lower material consumption, shorter deposition times)
- To analyse and optimise optical and electrical properties

Numerical modeling & simulation an important tool!

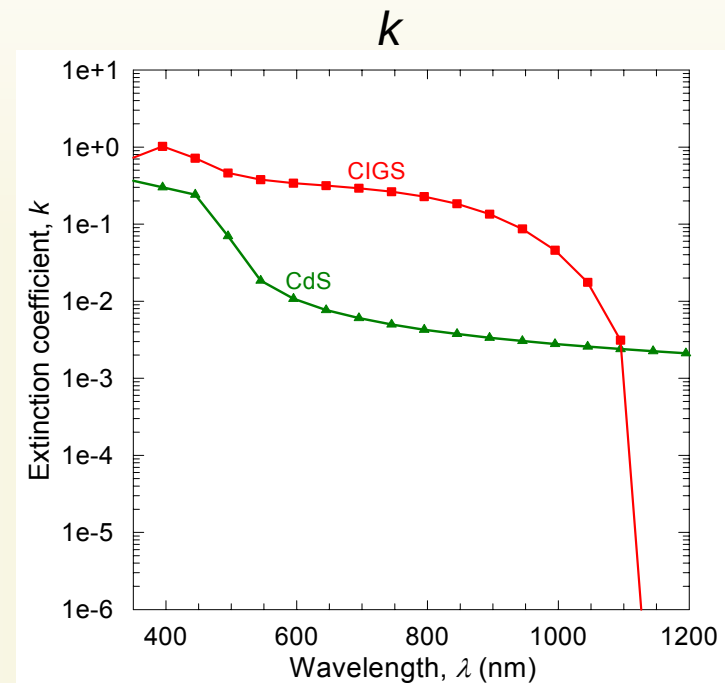
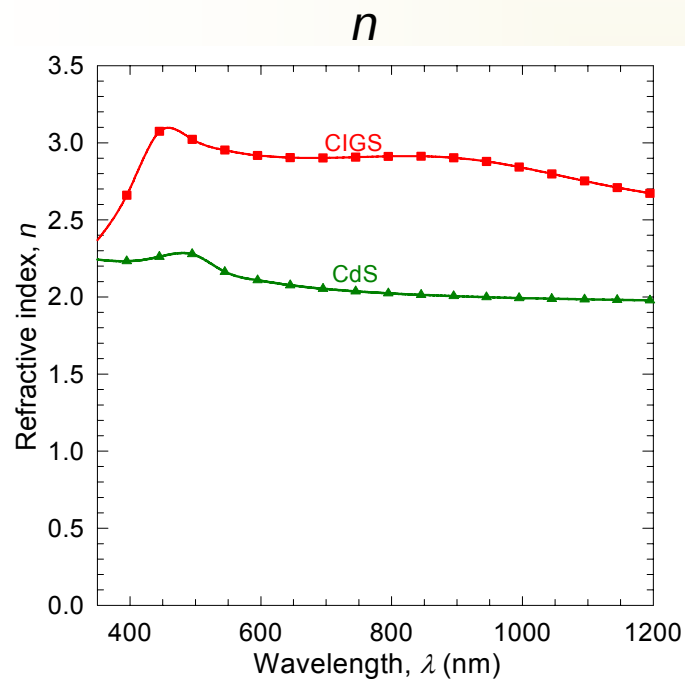


Simulations

Included in simulations:

- Experimentally obtained complex refractive indexes of layers

[O. Lundberg, PhD. Thesis, Uppsala University, 2003]



Simulations

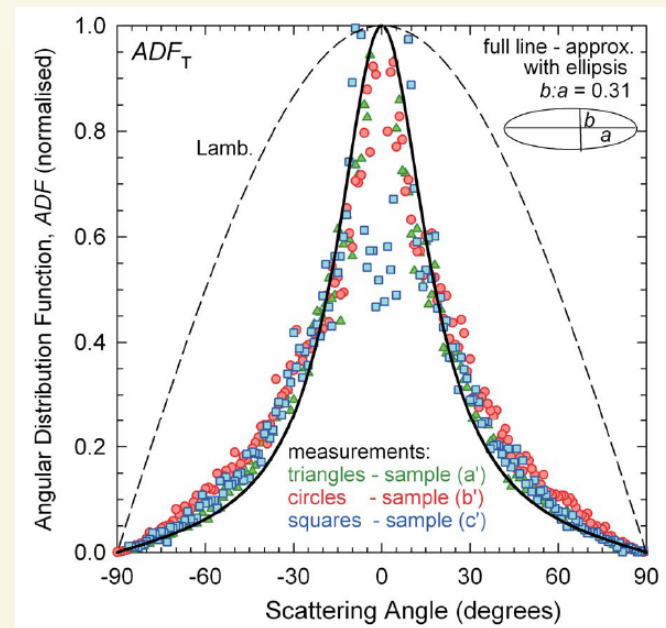
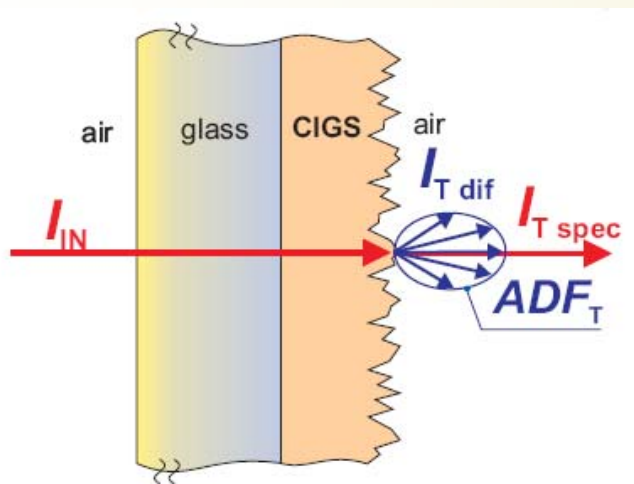
Included in simulations:

- Experimentally obtained complex refractive indexes of layers

[O. Lundberg, PhD. Thesis, Uppsala University, 2003]

- Measured H and ADF [J. Krc et al., Proc. of E-PVSEC, Barcelona, 2005, p. 1831.]

Example of ADF_T measurement:

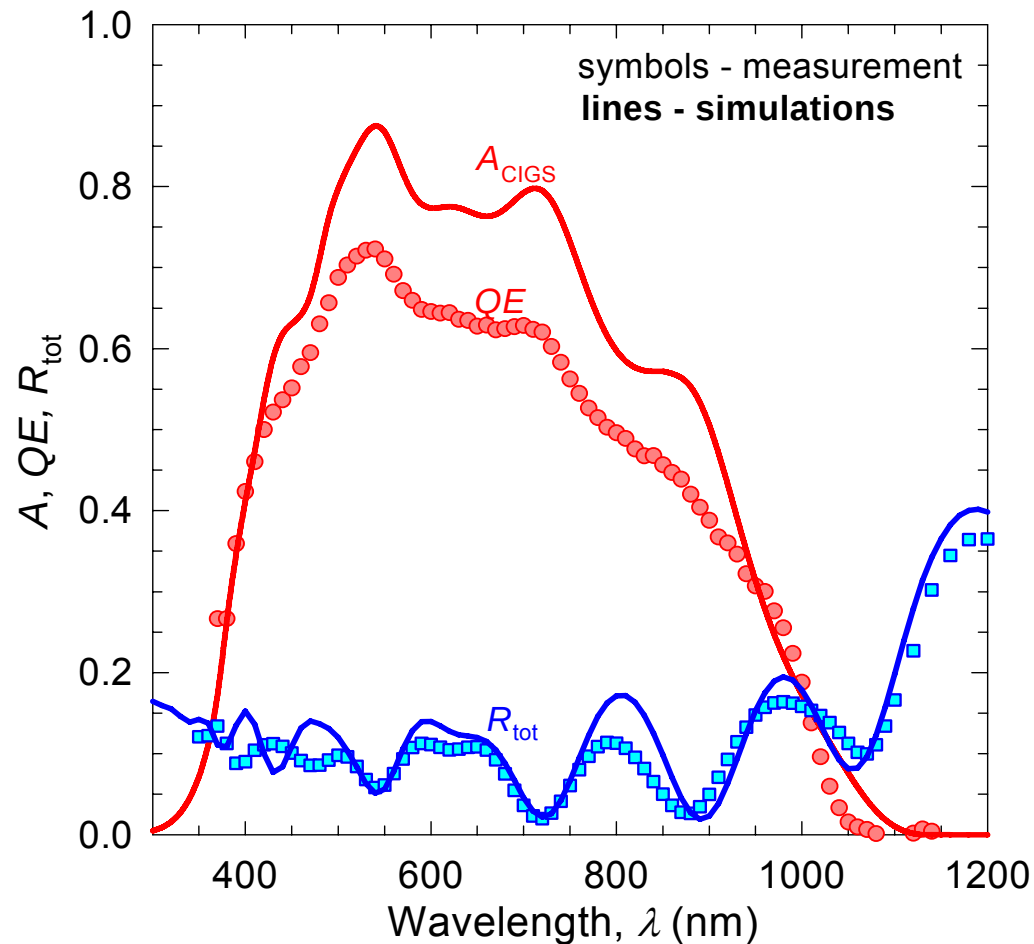




Simulation results

Simulation results

Total reflectance and quantum efficiency

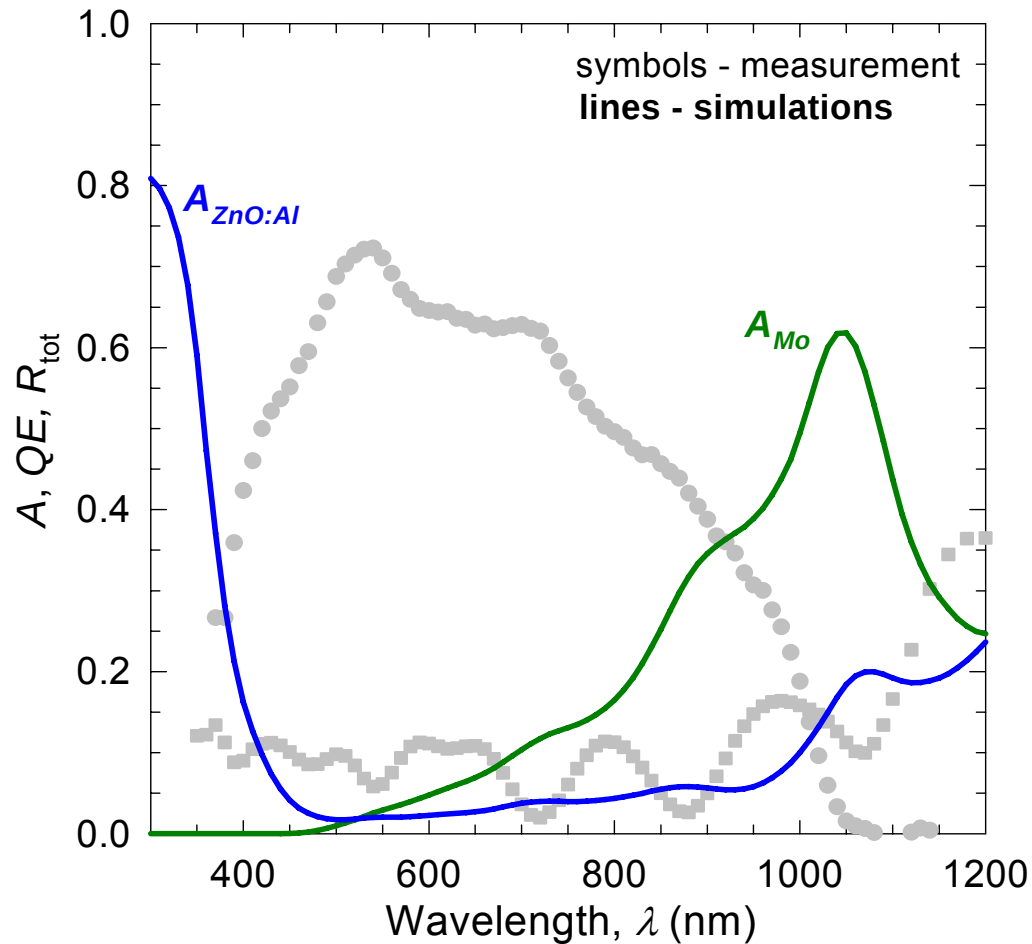


$$A_{\text{CIGS}} \rightarrow QE$$

*if ideal extraction of
charge carriers from
CIGS*

Simulation results

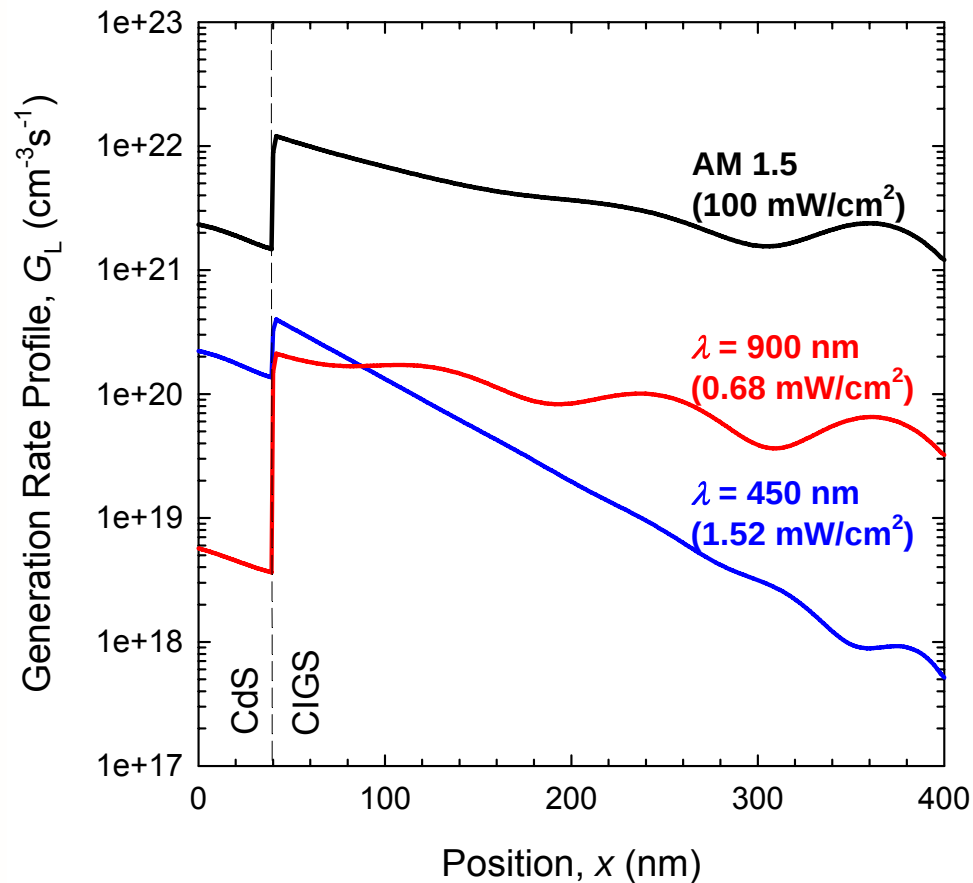
Absorptances in non-active layers



determination of optical losses in the structure

Simulation results

Charge-carrier generation-rate profile



*for further electrical
analysis of the structure*



Conclusions

- good agreement in sim. and meas. total reflectance of thin CIGS solar cell
- calibration of the simulator with realistic optical parameters (refractive indexes, scattering and others) is important
- starting point for optical optimisation and electrical analysis of the structure

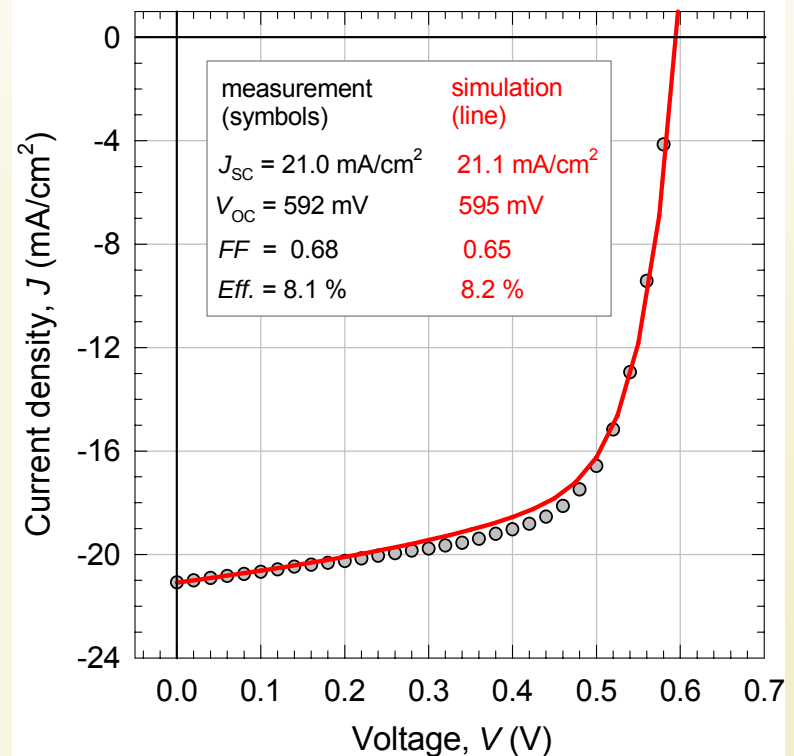
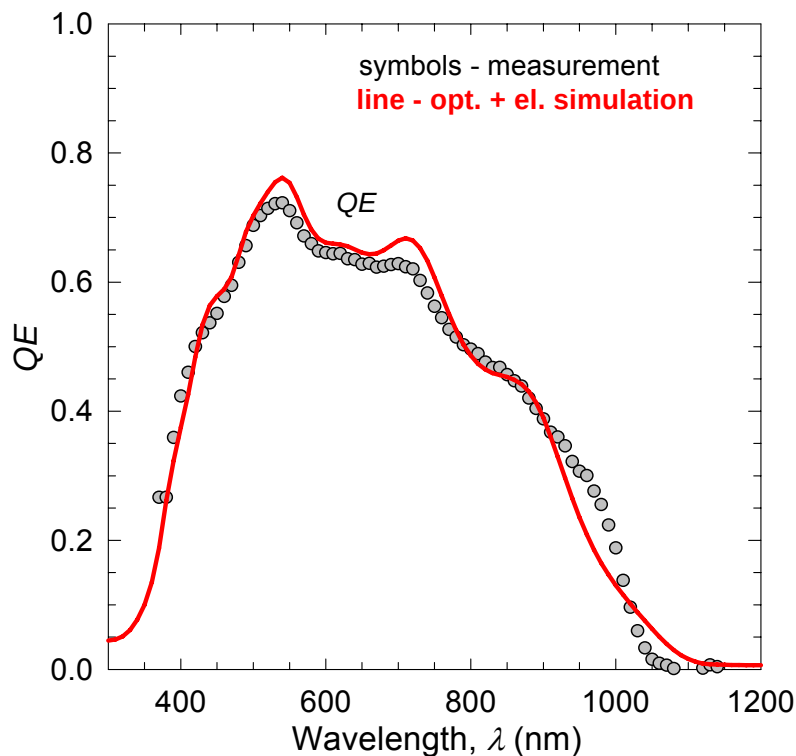


Further work

combined optical + electrical analysis of the structure

SunShine&Aspin simulators

External characteristics and parameters of the solar cell:

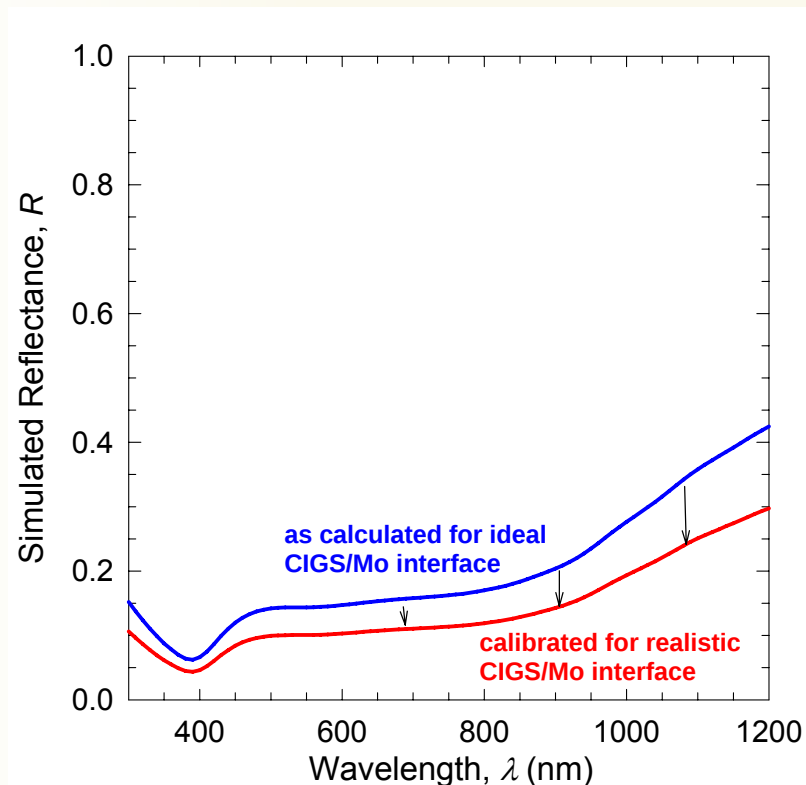


see extended NUSOD paper submitted to OQE

Simulation

Included in simulations:

- Reduced reflectance of CIGS/Mo interface by 30 %
(formation of MoSe_2 interfacial layer) [J. Krc et al., Proc. of E-PVSEC, Barcelona, 2005, p. 1831.]





Simulation

Haze of internal interfaces

Modified equations of scalar scattering theory:

$$H_R = 1 - e^{-\left(\frac{4\pi\sigma_{rms} \cdot c_R(\sigma_{rms}, \lambda)}{\lambda} n_1 \cos \varphi_{inc}\right)^2}$$

$$H_T = 1 - e^{-\left(\frac{4\pi\sigma_{rms} \cdot c_T(\sigma_{rms}, \lambda)}{\lambda} |n_1 \cos \varphi_{inc} - n_2 \cos \varphi_{out}|\right)^{2...3}}$$

c_R, c_T
calibration
functions

initial values:

$$c_R = 1$$

$$c_T = 0.5$$

P. Beckmann, A. Spizzichino, Pergamon Press (1963)

C.K. Carniglia, Optical Engineering 18/2 (1979)

M. Zeman et. al. JAP 88 (2000)

J. Krc et al. J. Appl. Phys. 92/2 (2002) 749-755.

J. Krc et al. Thin Solid Films 426/1-2 (2003) 296-304

basic theory

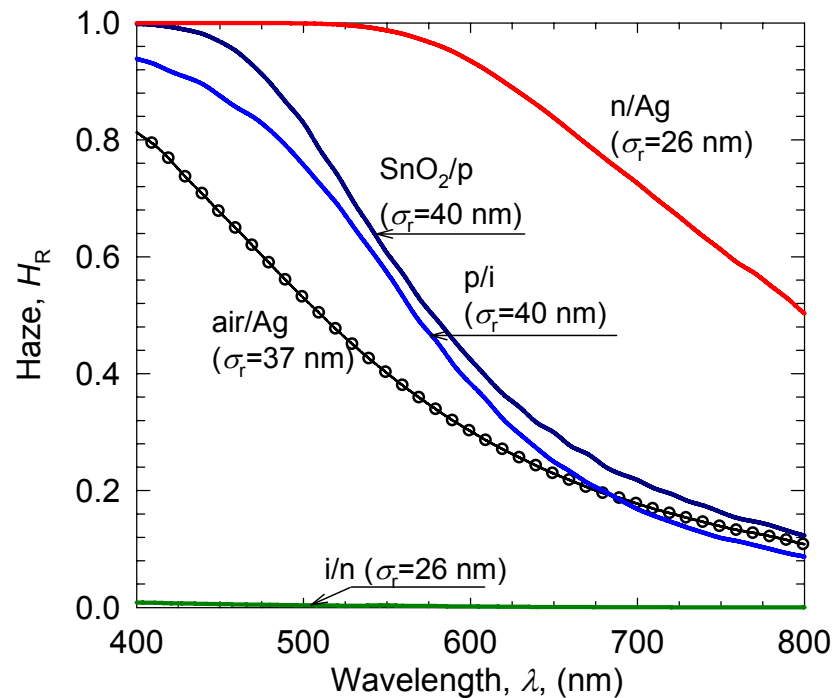
calibration introduced



Simulation

Application of the calibrated theory to internal interfaces

H_R



H_T

